



N-Channel 60-V (D-S) Fast Switching MOSFET

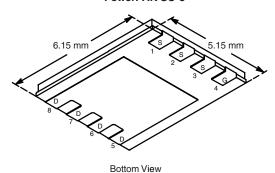
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
60	0.0096 at V _{GS} = 10 V	18		
	0.012 at V _{GS} = 4.5 V	16		

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFETs
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile

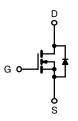


PowerPAK SO-8



Ordering Information: Si7460DP-T1-E3 (Lead (Pb)-free)

Si7460DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS TA	= 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	60		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current (T _{.1} = 150 °C) ^a	T _A = 25 °C	I _D	18	11	
Continuous Drain Current (1 _J = 150 °C)"	T _A = 70 °C		14	8	
Pulsed Drain Current		I _{DM}	40		Α
Continuous Source Current (Diode Conduction) ^a		I _S	4.3	1.6	
Avalanche Current		I _{AS}	50		
valanche Energy		E _{AS}	125		mJ
Manianum Davian Disainational	T _A = 25 °C	P _D	5.4	1.9	W
Maximum Power Dissipation ^a	T _A = 70 °C		3.4	1.2	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b,c}		_	260		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipulation to Applicate	t ≤ 10 s	R _{thJA}	18	23	°C/W
Maximum Junction-to-Ambient ^a	Steady State		52	65	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.0	1.3	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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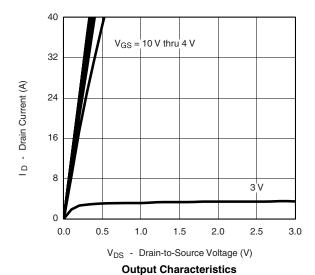


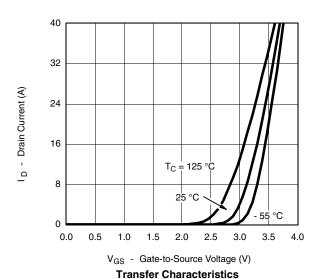
SPECIFICATIONS $T_J = 25$	°C, unless	otherwise noted					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = 250 \mu A$			3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current		V _{DS} = 60 V, V _{GS} = 0 V	V _{DS} = 60 V, V _{GS} = 0 V		1		
	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
Drain-Source On-State Resistance ^a	В	V _{GS} = 10 V, I _D = 18 A		0.008	0.0096	-	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 16 \text{ A}$	0.010		0.012	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 18 A		60		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 4.3 A, V _{GS} = 0 V		0.72	1.2	V	
Dynamic ^b	· · · · · · · · · · · · · · · · · · ·						
Total Gate Charge	Qg			65	100	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 18 \text{ A}$		10.5			
Gate-Drain Charge	Q _{gd}			16			
Turn-On Delay Time	t _{d(on)}			20	30		
Rise Time	t _r	V_{DD} = 30 V, R_L = 30 Ω		16	25	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		75	120		
Fall Time	t _f			30	45		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 4.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		41	65		

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





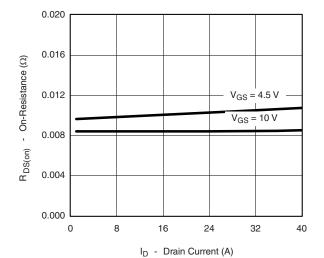
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.



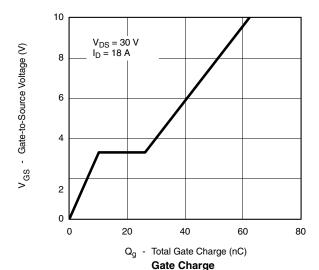


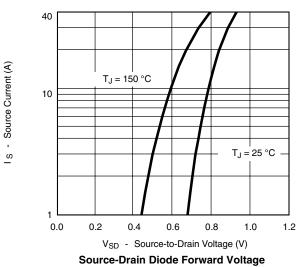


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current

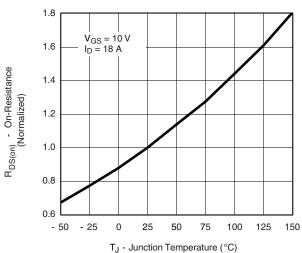




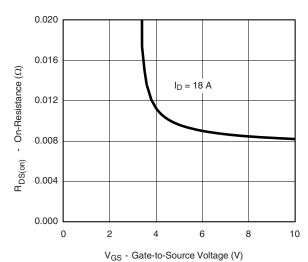
5000 4000 C_{iss} 3000 1000 C_{rss} 0 10 20 30 40 50 60

V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

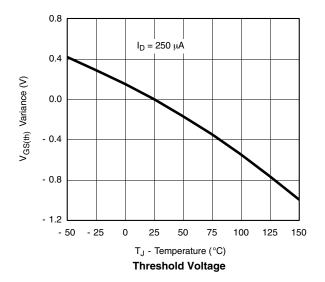


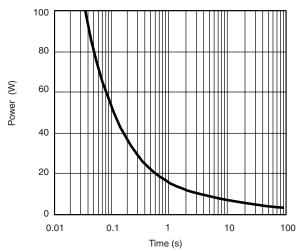
On-Resistance vs. Gate-to-Source Voltage

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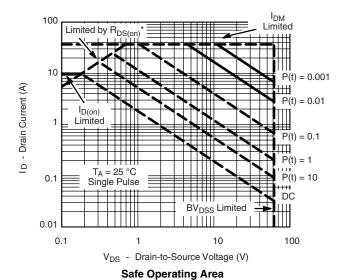
VISHAY

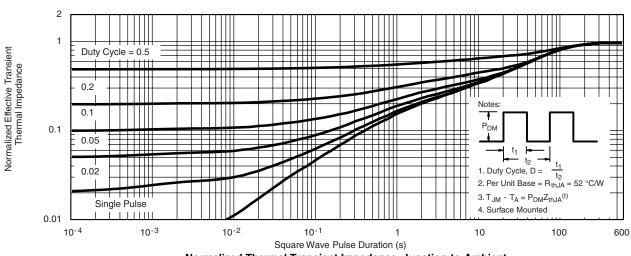
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Single Pulse Power, Junction-to-Ambient

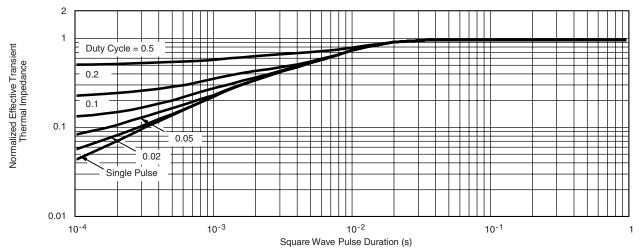




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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